



15A, 35V - 150V Dual Common Cathode Schottky Rectifiers

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- Guardring for overvoltage protection
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21







MECHANICAL DATA

Case: TO-263AB (D²PAK)

Molding compound, UL flammability classification rating 94V-0

Moisture sensitivity level: level 1, per J-STD-020 Part no. with suffix "H" means AEC-Q101 qualified

Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test

Polarity: As marked

Weight: 1.37 g (approximately)

PIN 1 O	к
	$-\circ$
PIN 2 O	HEATSINK

TO-263AB (D²PAK)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T _A =25°C unless otherwise noted)									
		MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	MBRS	
PARAMETER	SYMBOL	1535	1545	1550	1560	1590	15100	15150	Unit
		СТ	СТ	СТ	СТ	СТ	СТ	СТ	
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	90	100	150	V
Maximum RMS voltage	V_{RMS}	24	31	35	42	63	70	105	V
Maximum DC blocking voltage	V_{DC}	35	45	50	60	90	100	150	V
Maximum average forward rectified current	I _{F(AV)}	15						Α	
Peak repetitive forward current (Rated V _R , Square wave, 20KHz)	I _{FRM}	15			Α				
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load		150					Α		
Peak repetitive reverse surge current (Note 1)	I _{RRM}		1 0.5				Α		
Maximum instantaneous forward voltage (Note 2) I _F = 7.5 A, T _J =25°C			-	0.	75	0.	92	0.95	
I _F = 7.5 A, T _J =125°C	V_{F}	0.	57	0.	65	0.	82	0.92	V
I _F = 15 A, T _J =25°C		0.	84		-		-	-	
I _F = 15 A, T _J =125°C		0.	72		-		-	-	
T _J =25°C		0.1							
Maximum reverse current @ rated V _R T _J =125°C	I _R	15 1		10 5		5		mA	
Voltage rate of change (Rated V _R)	dV/dt	10000			V/µs				
Typical thermal resistance	$R_{ heta JC} \ R_{ heta JA}$	2 50			°C/W				
Operating junction temperature range	T _J	- 55 to +150					°C		
Storage temperature range	T _{STG}	- 55 to +150					°C		
Note 1: to = 2.0 up. 1.0KHz	-	•							

Note 1: tp = 2.0 μs, 1.0KHz

Note 2: Pulse test with PW=300µs, 1% duty cycle

1	ORDERING INFORMATION						
	PART NO.	PART NO.	PACKING CODE	PACKING CODE	PACKAGE	PACKING	
		SUFFIX		SUFFIX (*)			
	MBRS15xxCT	Н	RN	G	D ² PAK	800 / 13" Paper reel	
	(Note 1)	11	MN	T G D PAK	DPAK	800 / 13" Plastic reel	

Note 1: "xx" defines voltage from 35V (MBRS1535CT) to 150V (MBRS15150CT)

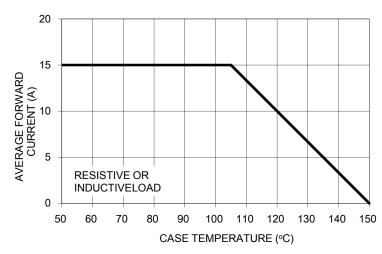
^{*:} Optional available

EXAMPLE					
PREFERRED P/N	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
MBRS1560CTHRNG	MBRS1560CT	Н	RN	G	AEC-Q101 qualified Green compound

RATINGS AND CHARACTERISTICS CURVES

(T_A=25°C unless otherwise noted)







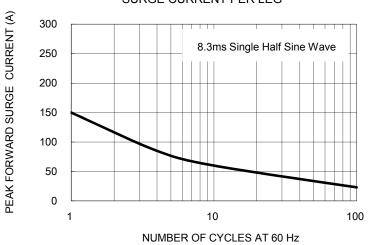


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

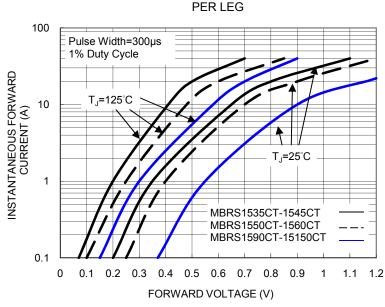
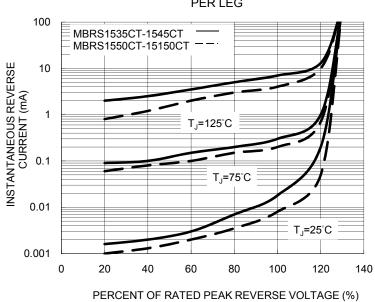


FIG. 4 TYPICAL REVERSE CHARACTERISTICS PER LEG





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FIG. 5 TYPICAL JUNCTION CAPACITANCE
PER LEG

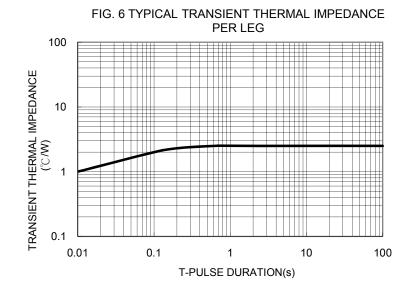
1000

(Ja)

WBRS1535CT-1545CT

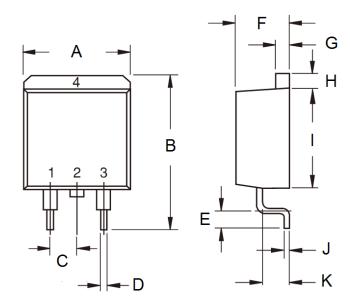
MBRS1535CT-1560CT

MBRS1590CT-15150CT



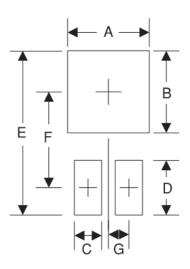
PACKAGE OUTLINE DIMENSIONS

TO-263AB (D²PAK)



DIM.	Unit	(mm)	Unit (inch)		
DIIVI.	Min	Max	Min	Max	
Α	ı	10.5	1	0.413	
В	14.60	15.88	0.575	0.625	
С	2.41	2.67	0.095	0.105	
D	0.68	0.94	0.027	0.037	
Е	2.29	2.79	0.090	0.110	
F	4.44	4.70	0.175	0.185	
G	1.14	1.40	0.045	0.055	
Н	1.14	1.40	0.045	0.055	
I	8.25	9.25	0.325	0.364	
J	0.36	0.53	0.014	0.021	
K	2.03	2.79	0.080	0.110	

SUGGESTED PAD LAYOUT



Symbol	Unit (mm)	Unit (inch)
А	10.8	0.425
В	8.3	0.327
С	1.1	0.043
D	3.5	0.138
E	16.9	0.665
F	9.5	0.374
G	2.5	0.098

MARKING DIAGRAM



P/N = Specific Device Code G = Green Compound

YWW = Date Code F = Factory Code



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